

# WN3S30S200CBT

**Dual power Schottky diode** 

Rev.01 - 21 April 2023

**Preliminary data sheet** 

#### **1. General description**

Dual common cathode power Schottky diode in TO263 (D2PAK) plastic package.



#### 2. Features and benefits

- High junction temperature up to 175 °C
- · Low forward voltage drop, negligible switching losses
- High efficiency

### 3. Applications

- DC to DC converters
- Freewheeling diode
- OR-ing diode
- Switched mode power supply rectifier

#### 4. Quick reference data

| able 1. Q          | uick reference data             |  |       |        |      |      |      |
|--------------------|---------------------------------|--|-------|--------|------|------|------|
| Symbol             | Parameter                       | Conditions   | Notes | Values |      |      | Unit |
| Absolute           | maximum rating                  |  |       |        |      |      |      |
| $V_{RRM}$          | repetitive peak reverse voltage |  |       |        | 200  |      | V    |
| I <sub>F(AV)</sub> | average forward current         | δ = 0.5 ; square-wave pulse; T <sub>mb</sub> ≤ 146 °C;<br>per diode; <u>Fig. 1</u> ; <u>Fig. 2</u> ; <u>Fig. 3</u> |       | 15     |      | A    |      |
| I <sub>O(AV)</sub> | average output current          | δ = 0.5 ; square-wave pulse; T <sub>mb</sub> ≤ 145 °C; both diodes conducting                                      |       | 30     |      | A    |      |
| Symbol             | Parameter                       | Conditions   | Notes | Min    | Тур  | Max  | Unit |
| Static ch          | aracteristics                   |  |       |        |      |      |      |
| V <sub>F</sub>     | forward voltage                 | $I_F = 15 \text{ A}; T_j = 25 \text{ °C}; \text{ per diode}; Fig. 6$   |       | -      | 0.88 | 0.95 | V    |
| I <sub>R</sub>     | reverse current                 | V <sub>R</sub> = 200 V; T <sub>i</sub> = 25 °C; per diode; <u>Fig. 7</u>   |       | -      | 0.04 | 5    | μA   |

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## 5. Pinning information

| Pin | Symbol | Description                         | Simplified outline | Graphic symbol |
|-----|--------|-------------------------------------|--------------------|----------------|
| 1   | A1     | anode 1                             |                    |                |
| 2   | К      | cathode                             |                    |                |
| 3   | A2     | anode 2                             | 0                  | K<br>sym125    |
| mb  | К      | mounting base; connected to cathode |                    |                |

#### 6. Ordering information

| Table 3. Ordering information |         |                       |         |               |         |             |  |  |
|-------------------------------|---------|-----------------------|---------|---------------|---------|-------------|--|--|
| Type number                   | Package | Orderable part number | Packing | Small packing | Package | Package     |  |  |
|                               | name    |                       | method  | quantity      | version | issue date  |  |  |
| WN3S30S200CBT                 | TO263   | WN3S30S200CBTJ        | Reel    | 800           | TO263d  | 17-Mar-2023 |  |  |

### 7. Marking

| Table 4. Marking codes |                   |
|------------------------|-------------------|
| Type number            | Marking codes     |
| WN3S30S200CBT          | WN3S30S<br>200CBT |

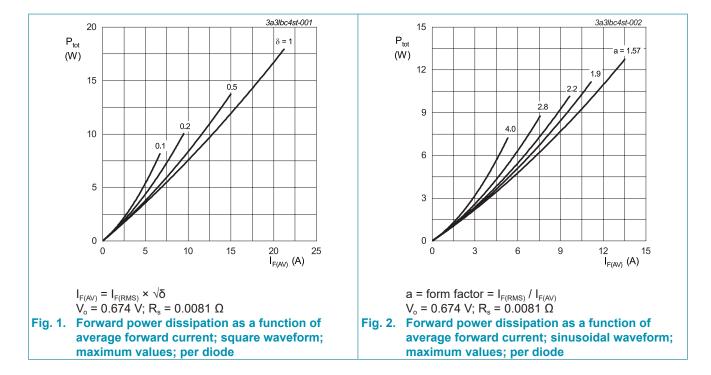
### 8. Limiting values

#### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

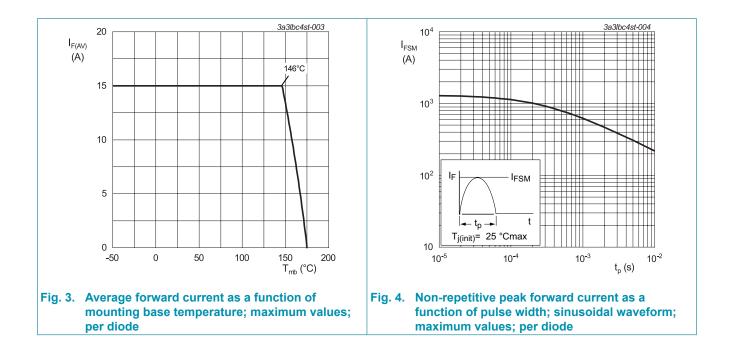
| Symbol             | Parameter                              | Conditions   | Notes | Values     | Unit |
|--------------------|--|--|-------|------------|------|
| $V_{\text{RRM}}$   | repetitive peak reverse voltage        |  |       | 200        | V    |
| $V_{\text{RWM}}$   | crest working reverse voltage          |  |       | 200        | V    |
| V <sub>R</sub>     | reverse voltage                        | DC   |       | 200        | V    |
| I <sub>F(AV)</sub> | average forward current                | δ = 0.5 ; square-wave pulse; T <sub>mb</sub> ≤ 146 °C;<br>per diode; <u>Fig. 1; Fig. 2; Fig. 3</u> |       | 15         | A    |
| I <sub>O(AV)</sub> | average output current                 | δ = 0.5 ; square-wave pulse; T <sub>mb</sub> ≤ 145 °C;<br>both diodes conducting                   |       | 30         | A    |
| I <sub>FSM</sub>   | non-repetitive peak<br>forward current | t <sub>p</sub> = 10 ms; T <sub>j(init)</sub> = 25 °C; sine-wave pulse;<br>per diode; <u>Fig. 4</u> |       | 220        | A    |
|                    |  | $t_p$ = 8.3 ms; $T_{j(init)}$ = 25 °C; sine-wave pulse; per diode                                  |       | 242        | A    |
| T <sub>stg</sub>   | storage temperature                    |  |       | -40 to 175 | °C   |
| Tj                 | junction temperature                   |  | [1]   | -40 to 175 | °C   |

[1] The heat generated must be less than the thermal conductivity from Junction to Ambient:  $dP_{tot}/dT_j < 1/R_{th(j-a)}$ 



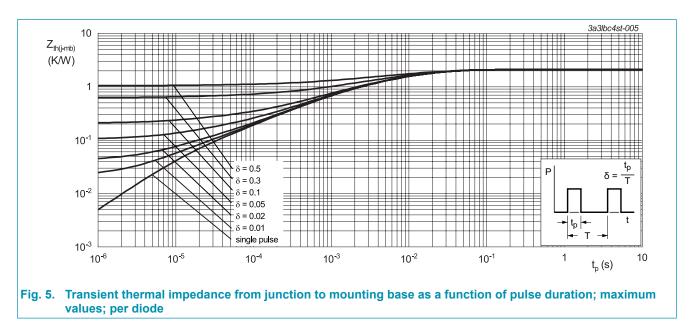
Dual power Schottky diode

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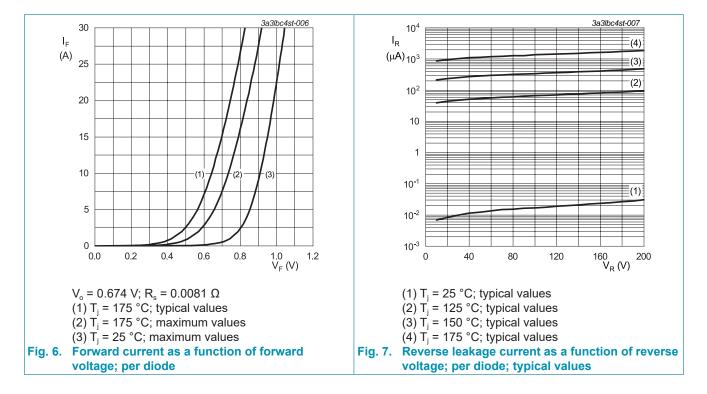
### 9. Thermal characteristics

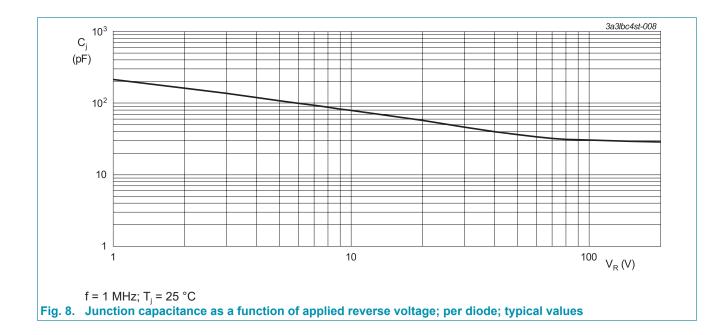
| Symbol                | Parameter  | Conditions               | Notes | Min | Тур | Max | Unit |
|-----------------------|--|--------------------------|-------|-----|-----|-----|------|
| $R_{\text{th(j-mb)}}$ | thermal resistance<br>from junction to<br>mounting base    | per diode; <u>Fig. 5</u> |       | -   | -   | 2.1 | K/W  |
|                       |  | both diodes conducting   |       | -   | -   | 1.1 | K/W  |
| $R_{\text{th(j-a)}}$  | thermal resistance<br>from junction to<br>ambient free air | in free air              |       | -   | 60  | -   | K/W  |



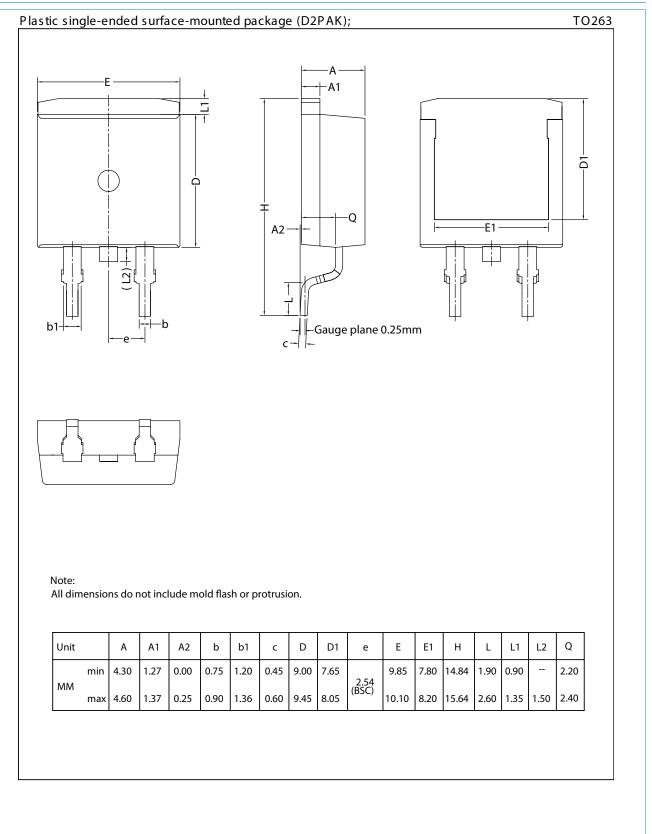
#### **10. Characteristics**

| Table 7. Cł    | naracteristics  |  |       |     |      |      |      |
|----------------|-----------------|--|-------|-----|------|------|------|
| Symbol         | Parameter       | Conditions   | Notes | Min | Тур  | Мах  | Unit |
| Static cha     | aracteristics   |  |       |     |      |      |      |
| V <sub>F</sub> | forward voltage | $I_F = 15 \text{ A}; T_j = 25 \text{ °C}; \text{ per diode}; Fig. 6$         |       | -   | 0.88 | 0.95 | V    |
|                |                 | $I_{F}$ = 15 A; $T_{j}$ = 125 °C; per diode                                  |       | -   | 0.77 | -    | V    |
|                |                 | I <sub>F</sub> = 15 A; T <sub>j</sub> = 175 °C; per diode; <u>Fig. 6</u>     |       | -   | 0.72 | 0.79 | V    |
| l <sub>R</sub> | reverse current | V <sub>R</sub> = 200 V; T <sub>j</sub> = 25 °C; per diode;<br><u>Fig. 7</u>  |       | -   | 0.04 | 5    | μA   |
|                |                 | V <sub>R</sub> = 200 V; T <sub>j</sub> = 125 °C; per diode;<br><u>Fig. 7</u> |       | -   | 0.1  | -    | mA   |





#### **11. Package outline**



# WN3S30S200CBT

### 12. Legal information

#### Data sheet status

| Document status [1][2]               | Product<br>status [3] | Definition  |
|--------------------------------------|-----------------------|---|
| Objective<br>[short] data<br>sheet   | Development           | This document contains data from<br>the objective specification for product<br>development. |
| Preliminary<br>[short] data<br>sheet | Qualification         | This document contains data from the preliminary specification.                             |
| Product<br>[short] data<br>sheet     | Production            | This document contains the product specification.   |

[1] Please consult the most recently issued document before initiating or completing a design.

- [2] The term 'short data sheet' is explained in section "Definitions".
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